NSN 5962-01-076-6622

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.440 inches	
Body Width:	
Between 0.240 inches and 0.325 inches	
Body Height:	
0.085 inches	
Maximum Power Dissipation Rating:	
910.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and monolithic and positive outputs and w/storage and programmable a	and programmed and bipolar and 3-state output
and schottky and high speed and expandable and w/buffered output and w/decoded output a	and w/enable and w/disable
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
75.00 nanoseconds propagation delay time, low to high level output	
Memory Device Type:	
Rom	
Test Data Document:	
82577-932820 standard (includes industry or association standards, individual manufacture	er standards, etc.).
Terminal Type And Quantity:	
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	

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